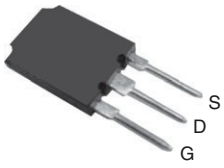
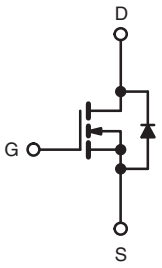
Power MOSFET

Super-247





N-Channel MOSFET

FEATURES

- Superfast body diode eliminates the need for External diodes in ZVS applications
- Lower gate charge results in simpler drive requirements
- Enhanced dV/dt capabilities offer improved ruggedness
- Higher gate voltage threshold offers improved noise immunity
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

Pb-free

RoHS COMPLIANT

HALOGEN FREE

APPLICATIONS

- Zero voltage switching SMPS
- Telecom and server power supplies
- Uninterruptible power supplies
- Motor control applications

PRODUCT SUMMARY		
V_{DS} (V)	500	
$R_{DS(on)}$ (Ω)	V_{GS} = 10 V	0.087
Q_g (Max.) (nC)	380	
Q_{gs} (nC)	80	
Q_{gd} (nC)	190	
Configuration	Single	

ORDERING INFORMATION	
Package	Super-247
Lead (Pb)-free and halogen free	SiHFPS40N50L-GE3

ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C, unless otherwise noted)

PARAMETER			SYMBOL	LIMIT	UNIT
Drain-source voltage			V_{DS}	500	V
Gate-source voltage			V_{GS}	± 30	
Continuous drain current	V_{GS} at 10 V	T_C = 25 °C	I_D	46	A
		T_C = 100 °C		29	
Pulsed drain current [a]			I_{DM}	180	
Linear derating factor				4.3	W/°C
Single pulse avalanche energy [b]			E_{AS}	920	mJ
Repetitive avalanche current [a]			I_{AR}	46	A
Repetitive avalanche Energy [a]			E_{AR}	54	mJ
Maximum power dissipation	T_C = 25 °C		P_D	540	W
Peak diode recovery dV/dt [c]			dV/dt	34	V/ns
Operating junction and storage temperature range			T_J, T_{stg}	- 55 to + 150	°C
Soldering recommendations (peak temperature)	for 10 s			300 [d]	

Notes

a. Repetitive rating; pulse width limited by maximum junction temperature (see fig. 11)
b. Starting T_J = 25 °C, L = 0.86 mH, R_g = 25 Ω, I_{AS} = 46 A (see fig. 12)
c. $I_{SD} \leq$ 46 A, dI/dt ≤ 550 A/μs, $V_{DD} \leq V_{DS}$, $T_J \leq$ 150 °C
d. 1.6 mm from case

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THERMAL RESISTANCE RATINGS				
PARAMETER	**SYMBOL**	**TYP.**	**MAX.**	**UNIT**
Maximum junction-to-ambient [a]	R_{thJA}	-	40	°C/W
Case-to-sink, flat, greased surface	R_{thCS}	0.24	-	
Maximum junction-to-case (drain) [a]	R_{thJC}	-	0.23	

Note

a. R_{th} is measured at T_J approximately 90 °C

SPECIFICATIONS (T_J = 25 °C, unless otherwise noted)							
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static							
Drain-source breakdown voltage	V_{DS}	V_{GS} = 0 V, I_D = 250 µA		500	-	-	V
V_{DS} temperature coefficient	$\Delta V_{DS}/T_J$	Reference to 25 °C, I_D = 1 mA		-	0.60	-	V/°C
Gate-source threshold voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 µA		3.0	-	5.0	V
Gate-source leakage	I_{GSS}	V_{GS} = ± 30 V		-	-	± 100	nA
Zero gate voltage drain current	I_{DSS}	V_{DS} = 500 V, V_{GS} = 0 V		-	-	50	µA
		V_{DS} = 400 V, V_{GS} = 0 V, T_J = 125 °C		-	-	2.0	mA
Drain-source on-state resistance	$R_{DS(on)}$	V_{GS} = 10 V	I_D = 28 A [b]	-	0.087	0.100	Ω
Forward transconductance	g_{fs}	V_{DS} = 50 V, I_D = 46 A		21	-	-	S
Dynamic							
Input capacitance	C_{iss}	V_{GS} = 0 V, V_{DS} = 25 V, f = 1.0 MHz, see fig. 5		-	8110	-	pF
Output capacitance	C_{oss}			-	960	-	
Reverse transfer capacitance	C_{rss}			-	130	-	
Output capacitance	C_{oss}	V_{GS} = 0 V	V_{DS} = 1.0 V, f = 1.0 MHz	-	11200	-	
			V_{DS} = 400 V, f = 1.0 MHz	-	240	-	
Effective output capacitance	C_{oss} eff.		V_{DS} = 0 V to 400 V [c]	-	440	-	
Effective output capacitance (energy related)	$C_{oss\ eff.}$ (ER)			-	310	-	
Total gate charge	Q_g	V_{GS} = 10 V	I_D = 46 A, V_{DS} = 400 V, see fig. 7 and 15 [b]	-	-	380	nC
Gate-source charge	Q_{gs}			-	-	80	
Gate-drain charge	Q_{gd}			-	-	190	
Internal gate resistance	R_g	f = 1 MHz, open drain		-	0.90	-	Ω
Turn-on delay time	$t_{d(on)}$	V_{DD} = 250 V, I_D = 46 A, R_g = 0.85 Ω, V_{GS} = 10 V, see fig. 14a and 14b [b]		-	27	-	ns
Rise time	t_r			-	170	-	
Turn-off delay time	$t_{d(off)}$			-	50	-	
Fall time	t_f			-	69	-	
Drain-source body diode characteristics							
Continuous source-drain diode current	I_S	MOSFET symbol showing the integral reverse p - n junction diode 		-	-	46	A
Pulsed diode forward current [a]	I_{SM}			-	-	180	
Body diode voltage	V_{SD}	T_J = 25 °C, I_S = 46 A, V_{GS} = 0 V [b]		-	-	1.5	V
Body diode reverse recovery time	t_{rr}	T_J = 25 °C, I_F = 46 A		-	170	250	ns
		T_J = 125 °C, dI/dt = 100 A/µs [b]		-	220	330	
Body diode reverse recovery charge	Q_{rr}	T_J = 25 °C, I_S = 46 A, V_{GS} = 0 V [b]		-	705	1060	nC
		T_J = 125 °C, dI/dt = 100 A/µs [b]		-	1.3	2.0	
Reverse recovery current	I_{RRM}	T_J = 25 °C		-	9.0	-	A
Forward turn-on time	t_{on}	Intrinsic turn-on time is negligible (turn-on is dominated by L_S and L_D)					

Notes

a. Repetitive rating; pulse width limited by maximum junction temperature (see fig. 11)
b. Pulse width ≤ 400 µs; duty cycle ≤ 2 %
c. C_{oss} eff. is a fixed capacitance that gives the same charging time as C_{oss} while V_{DS} is rising from 0 % to 80 % V_{DS}
C_{oss} eff. (ER) is a fixed capacitance that stores the same energy as C_{oss} while V_{DS} is rising from 0 % to 80 % V_{DS}

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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

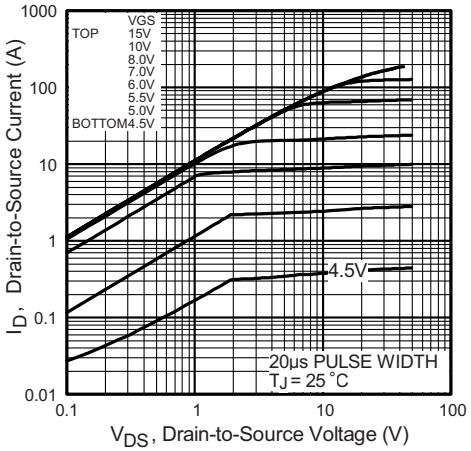


Fig. 1 - Typical Output Characteristics

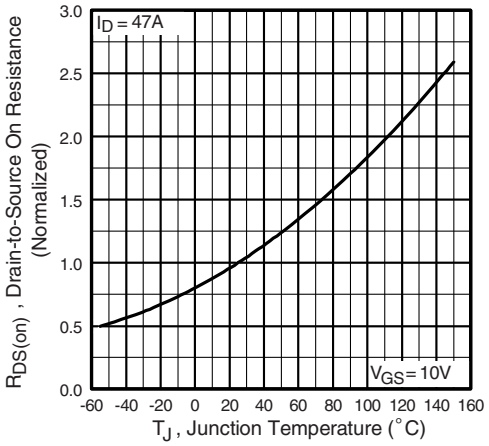


Fig. 4 - Normalized On-Resistance vs. Temperature

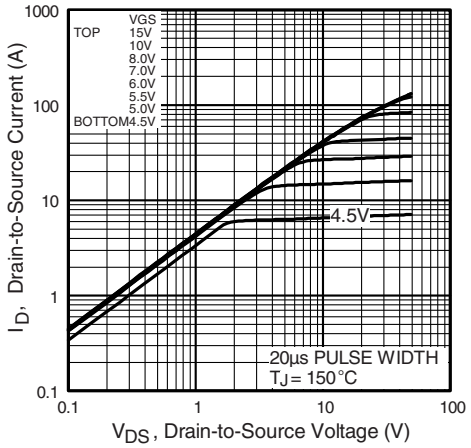


Fig. 2 - Typical Output Characteristics

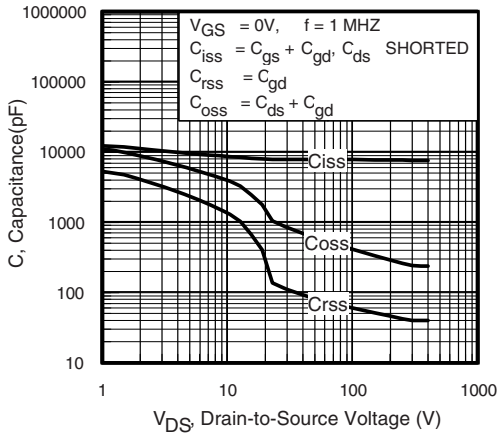


Fig. 5 - Typical Capacitance vs. Drain-to-Source Voltage

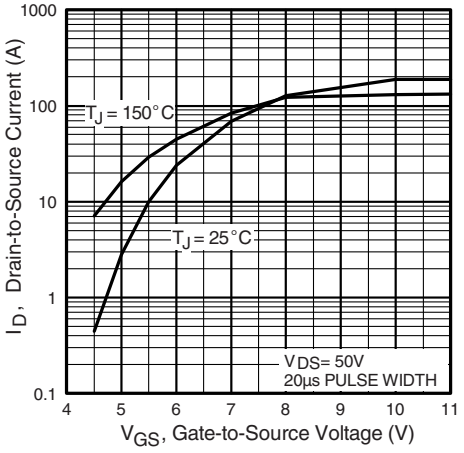


Fig. 3 - Typical Transfer Characteristics

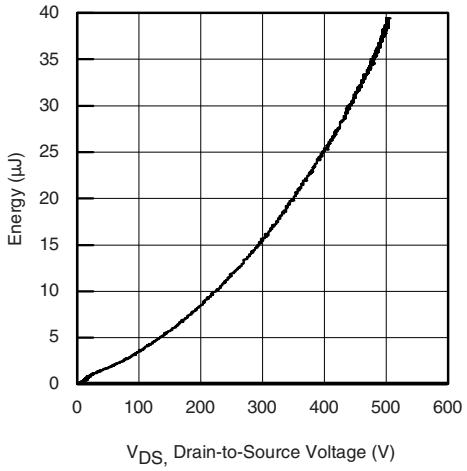


Fig. 6 - Typical Output Capacitance Stored Energy vs. V_{DS}

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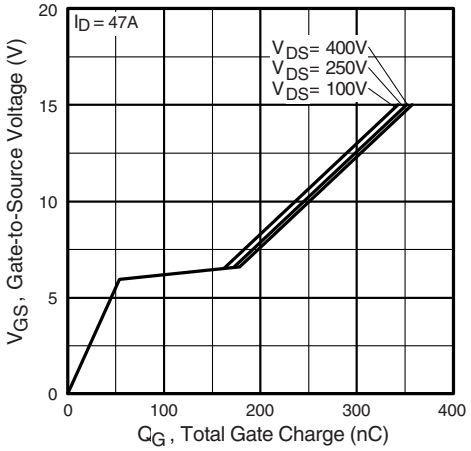


Fig. 7 - Typical Gate Charge vs. Gate-to-Source Voltage

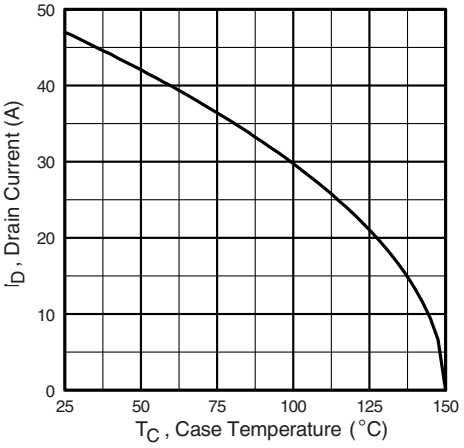


Fig. 9 - Maximum Drain Current vs. Case Temperature

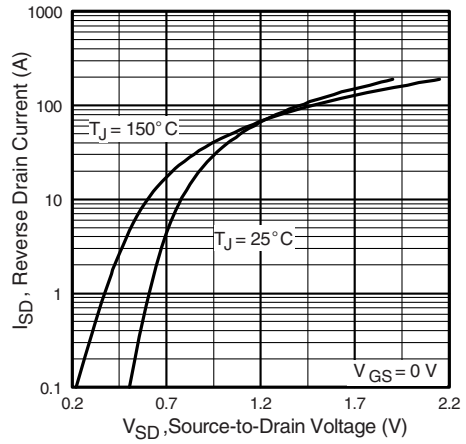


Fig. 8 - Typical Source Drain Diode Forward Voltage

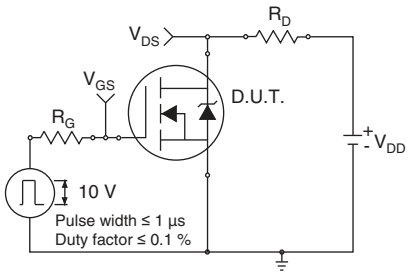


Fig. 10a - Switching Time Test Circuit

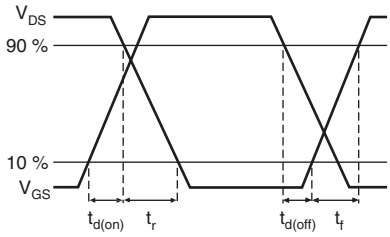


Fig. 10b - Switching Time Waveforms

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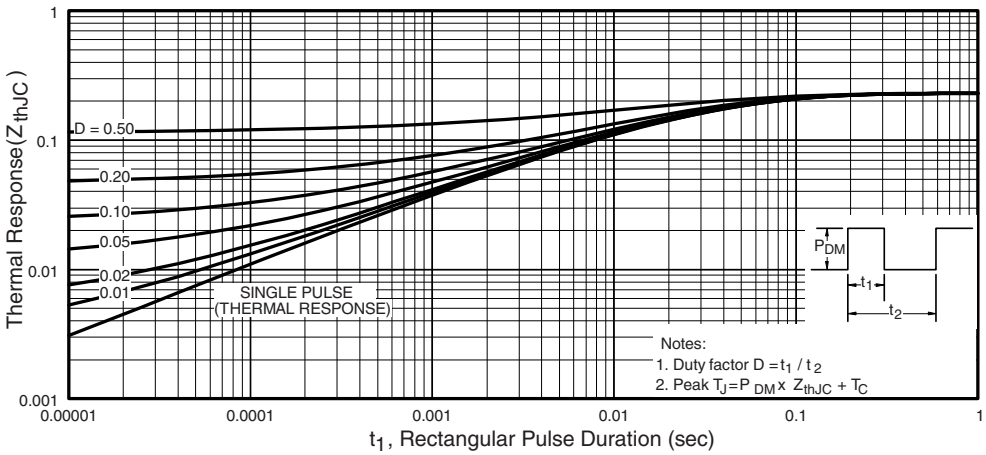


Fig. 11 - Maximum Effective Transient Thermal Impedance, Junction-to-Case

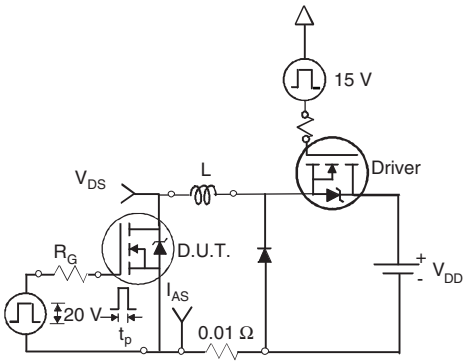


Fig. 12a - Unclamped Inductive Test Circuit

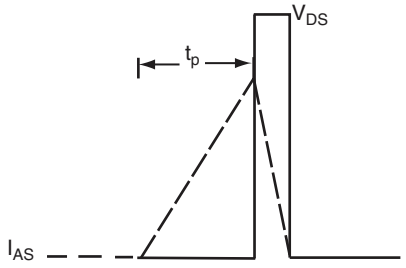


Fig. 12b - Unclamped Inductive Waveforms

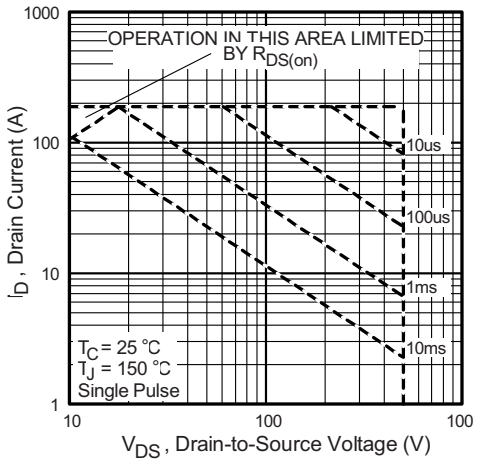


Fig. 12c - Maximum Avalanche Energy vs. Drain Current

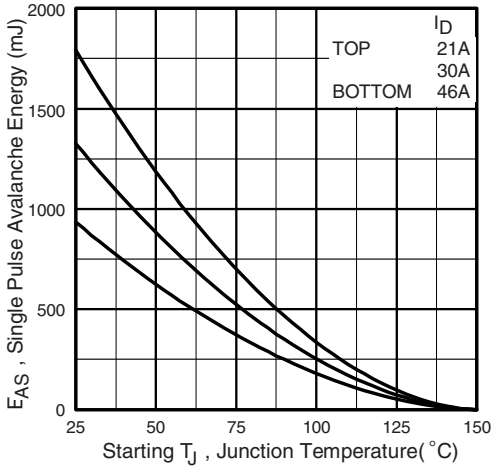


Fig. 12d - Maximum Safe Operating Area

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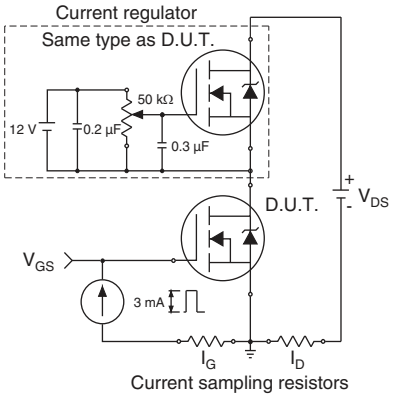


Fig. 13a - Gate Charge Test Circuit

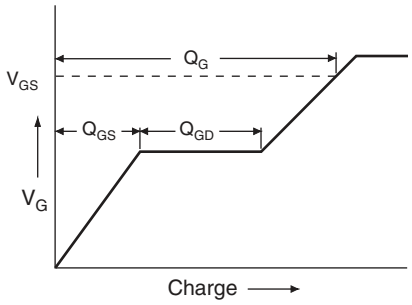
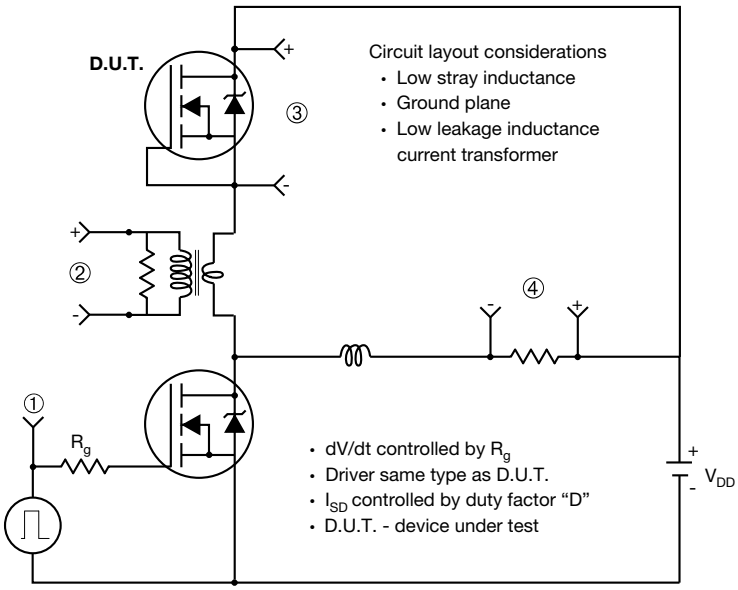
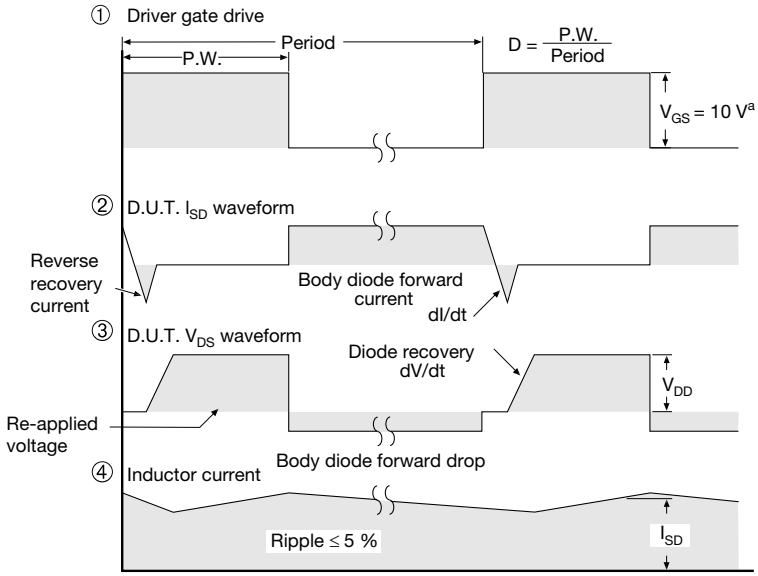


Fig. 13b - Basic Gate Charge Waveform

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Peak Diode Recovery dV/dt Test Circuit





Note

a. V_{GS} = 5 V for logic level devices

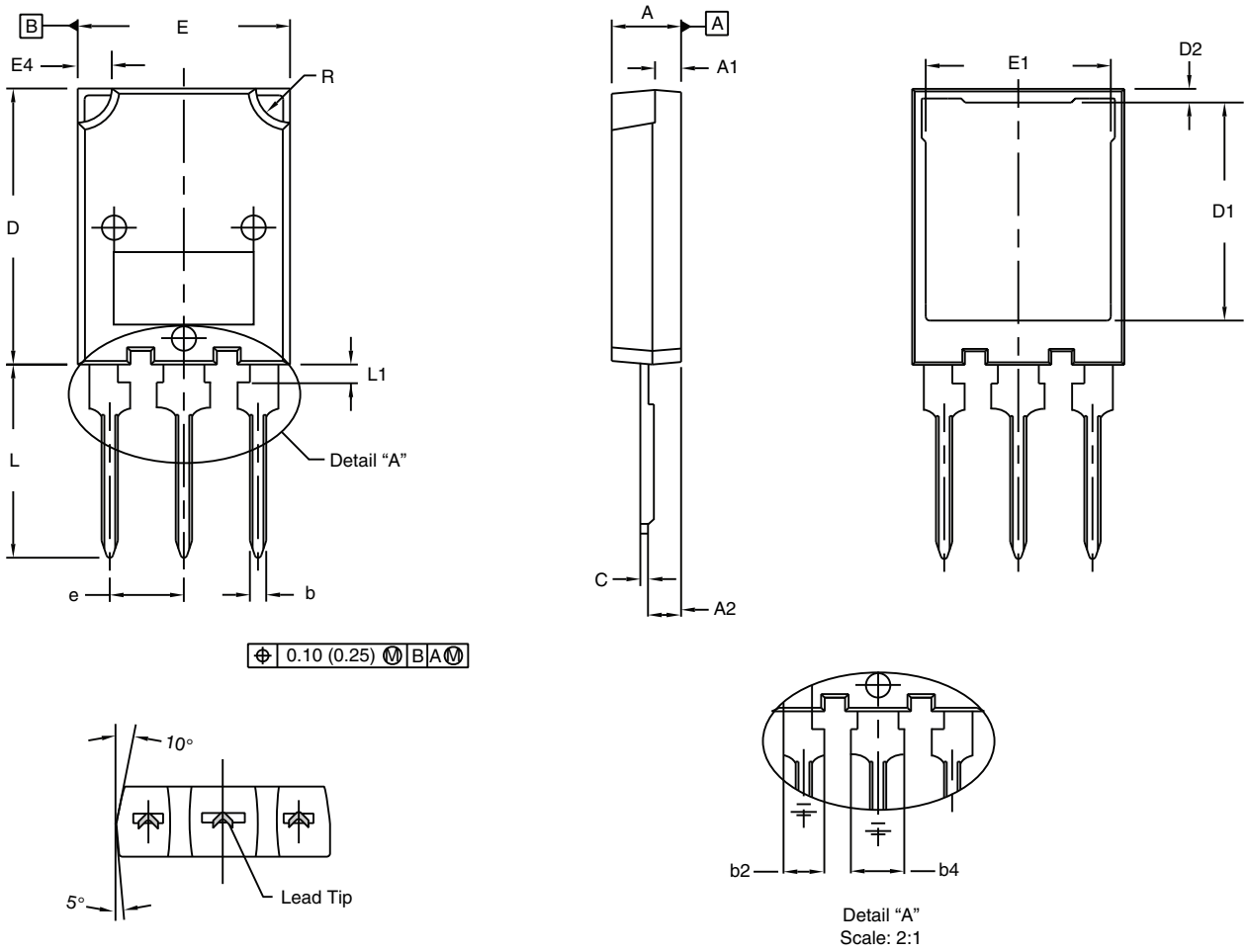
Fig. 14 - For N-Channel

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TO-274AA (High Voltage)

VERSION 1: FACILITY CODE = Y



	MILLIMETERS		INCHES	
DIM.	MIN.	MAX.	MIN.	MAX.
A	4.70	5.30	0.185	0.209
A1	1.50	2.50	0.059	0.098
A2	2.25	2.65	0.089	0.104
b	1.30	1.60	0.051	0.063
b2	1.80	2.20	0.071	0.087
b4	3.00	3.25	0.118	0.128
c (1)	0.38	0.89	0.015	0.035
D	19.80	20.80	0.780	0.819

	MILLIMETERS		INCHES	
DIM.	MIN.	MAX.	MIN.	MAX.
D1	15.50	16.10	0.610	0.634
D2	0.70	1.30	0.028	0.051
E	15.10	16.10	0.594	0.634
E1	13.30	13.90	0.524	0.547
e	5.45 BSC		0.215 BSC	
L	13.70	14.70	0.539	0.579
L1	1.00	1.60	0.039	0.063
R	2.00	3.00	0.079	0.118

Notes

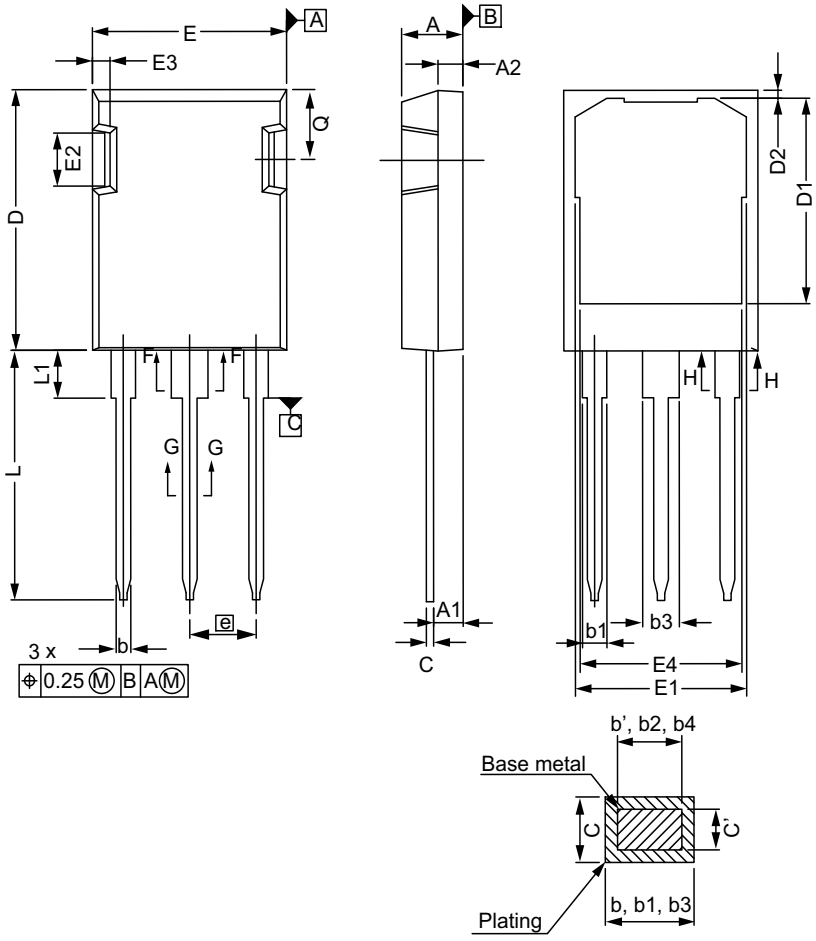
- Dimensioning and tolerancing per ASME Y14.5M-1994
- Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outer extremes of the plastic body
- Outline conforms to JEDEC® outline to TO-274AA

(1) Dimension measured at tip of lead

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VERSION 2: FACILITY CODE = N



SECTION "F-F", "G-G" AND "H-H"
SCALE: NONE

	MILLIMETERS	
DIM.	MIN.	MAX.
A	4.83	5.21
A1	2.29	2.54
A2	1.91	2.16
b'	1.07	1.28
b	1.07	1.33
b1	1.91	2.41
b2	1.91	2.16
b3	2.87	3.38
b4	2.87	3.13
c'	0.55	0.65
c	0.55	0.68
D	20.80	21.10

	MILLIMETERS	
DIM.	MIN.	MAX.
D1	16.25	17.65
D2	0.50	0.80
E	15.75	16.13
E1	13.10	14.15
E2	3.68	5.10
E3	1.00	1.90
E4	12.38	13.43
e	5.44 BSC	
N	3	
L	19.81	20.32
L1	3.70	4.00
Q	5.49	6.00

ECN: E20-0538-Rev. C, 19-Oct-2020
DWG: 5975

Notes

- Dimensioning and tolerancing per ASME Y14.5M-1994
- Outline conforms to JEDEC® outline to TO-274AD
- Dimensions are measured in mm, angles are in degree
- Metal surfaces are tin plated, except area of cut

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Parça koduyla arama

Üretici parça numarasını yazın; stok ve fiyatı hemen görün.

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Ürün kategorileri

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